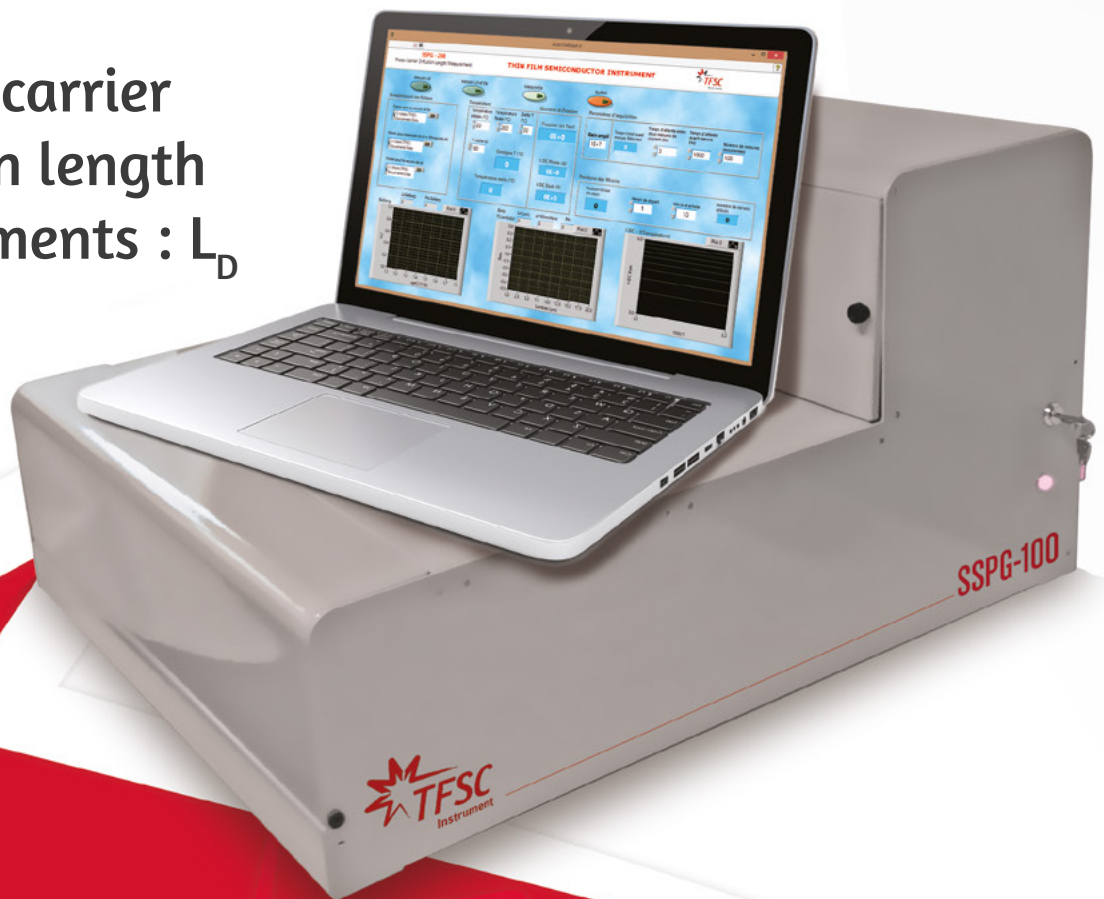




# Active thin film quality optimization for Silicon and Organic

Photo-carrier diffusion length measurements :  $L_D$



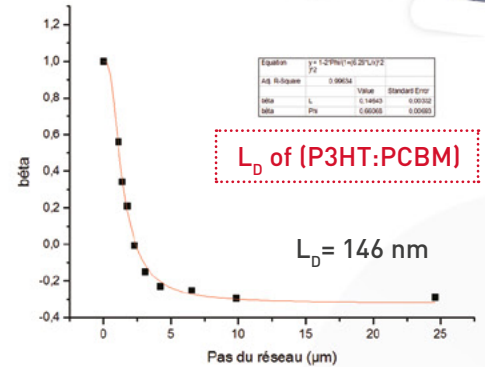
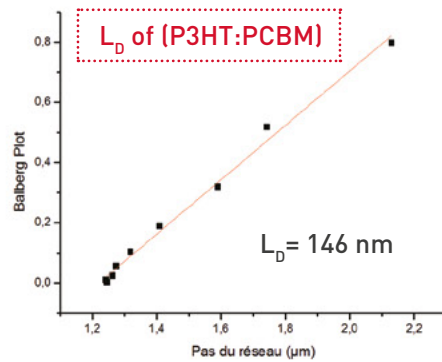
- ✓ **Less than 5 mn** measurement
- ✓ **Direct** measurement : no need to measure carrier mobility and lifetime to deduce  $L_D$
- ✓ **Direct** link to device performances

PARTNERS

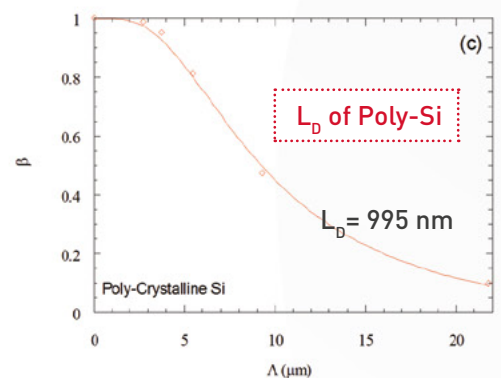
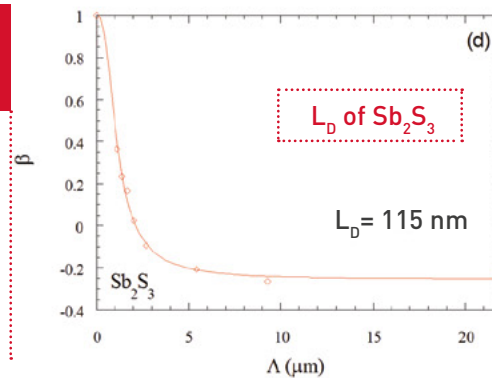


# Typical data

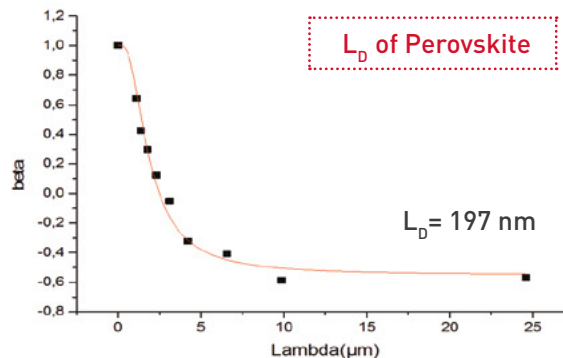
- Measurement on Organic layers:
- Successful measurement
- First data to be published worldwide



## Measurements on non-organic layers



## Measurements on Perovskite layers



## Product features and specifications

- Measurement based on SSPG method (Steady State Phocarrier Grating)
- Measurement range of diffusion length: from 10 nm to 10  $\mu\text{m}$
- Material type: Non-organic, Organic(BHJ), Perovskite...

- Sample conditions: from atmosphere to vacuum, under variable temperatures
- Option 1: sample under vacuum
- Option 2: sample heated up to 200 °C
- Equipment size: 604x754x327 mm

## To contact us

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